

SBOS307C - MAY 2004 - REVISED DECEMBER 2004

# **CURRENT SHUNT MONITOR**

# -16V to +80V Common-Mode Range

# FEATURES

- WIDE COMMON-MODE VOLTAGE: -16V to +80V
- LOW ERROR: 3.0% Over Temp (max)
- BANDWIDTH: Up to 500kHz
- THREE TRANSFER FUNCTIONS AVAILABLE: 20V/V, 50V/V, and 100V/V
- QUIESCENT CURRENT: 900μA (max)
- COMPLETE CURRENT SENSE SOLUTION

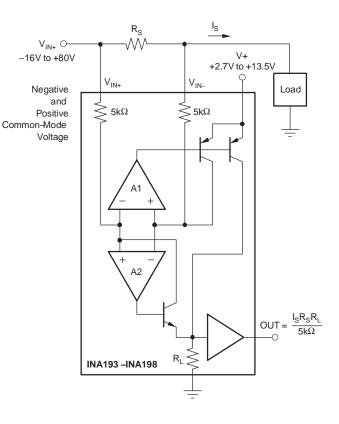
# **APPLICATIONS**

- WELDING EQUIPMENT
- NOTEBOOK COMPUTERS
- CELL PHONES
- TELECOM EQUIPMENT
- AUTOMOTIVE
- POWER MANAGEMENT
- BATTERY CHARGERS

# DESCRIPTION

The INA193—INA198 family of current shunt monitors with voltage output can sense drops across shunts at common-mode voltages from –16V to +80V, independent of the INA19x supply voltage. They are available with three output voltage scales: 20V/V, 50V/V, and 100V/V. The 500kHz bandwidth simplifies use in current control loops. The INA193—INA195 provide identical functions but alternative pin configurations to the INA196—INA198, respectively.

The INA193—INA198 operate from a single +2.7V to +13.5V supply, drawing a maximum of 900 $\mu$ A of supply current. They are specified over the extended operating temperature range (-40°C to +125°C), and are offered in a space-saving SOT23 package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.



SBOS307C - MAY 2004 - REVISED DECEMBER 2004

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage +18V
Analog Inputs, V <sub>IN+</sub> , V <sub>IN</sub>
Differential (V <sub>IN+</sub> ) – (V <sub>IN-</sub> ) –2V to +2V
Common-Mode <sup>(2)</sup>
Analog Output, $Out^{(2)}$ $GND - 0.3V$ to $(V+) + 0.3V$
Input Current Into Any Pin <sup>(2)</sup> 5mA
Operating Temperature55°C to +150°C
Storage Temperature65°C to +150°C
Junction Temperature
Lead Temperature (soldering, 10s)+300°C
ESD Ratings
Human Body Model 4000V
Charged-Device Model 1000V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

(2) Input voltage at any pin may exceed the voltage shown if the current at that pin is limited to 5mA.

# PACKAGE INFORMATION<sup>(1)</sup>



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

RUMENTS

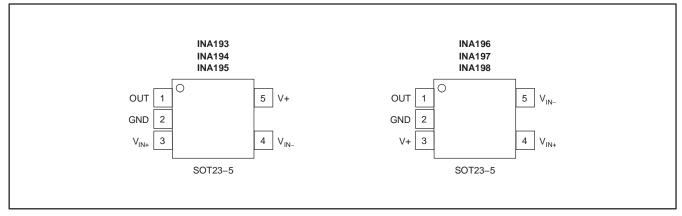
www.ti.com

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	PACKAGE MARKING
INA193	SOT23-5	DBV	BJJ
INA194	SOT23-5	DBV	BJI
INA195	SOT23-5	DBV	BJK
INA196	SOT23-5	DBV	BJE
INA197	SOT23-5	DBV	BJH
INA198	SOT23-5	DBV	BJL

(1) For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet, or refer to our web site at www.ti.com.

# **PIN ASSIGNMENTS**





ELECTRICAL CHARACTERISTICS:  $V_S = +12V$ Boldface limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to  $+125^{\circ}C$ .

All specifications at  $T_A = +25^{\circ}C$ ,  $V_S = +12V$ ,  $V_{IN+} = 12V$ , and  $V_{SENSE} = 100$ mV, unless otherwise noted.

PARAMETER			INA INA			
		TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
INPUT						
Full-Scale Input Voltage	VSENSE	$V_{SENSE} = V_{IN+} - V_{IN-}$		0.15	(V <sub>S</sub> – 0.2)/Gain	V
Common-Mode Input Range	VCM		-16		80	v
Common-Mode Rejection	CMR	$V_{IN+} = -16V \text{ to } +80V$	80	94		dB
Over Temperature		V <sub>IN+</sub> = +12V to +80V	100	120		dB
Offset Voltage, RTI	Vos			±0.5	2	mV
Over Temperature				0.5	3	mV
vs Temperature	dV <sub>OS</sub> /dT			2.5		μ <b>ν/</b> °C
vs Power Supply	PSR	V <sub>S</sub> = +2.7V to +13.5V, V <sub>IN+</sub> = +13.5V		5	100	μ <b>V/V</b>
Input Bias Current, V <sub>IN</sub> pin	۱ <sub>B</sub>			±8	±16	μΑ
OUTPUT						
Gain: INA193, INA196	G			20		V/V
INA194, INA197				50		V/V
INA195, INA198				100		V/V
Gain Error		$V_{SENSE} = 20 \text{mV}$ to 100 mV, $T_{A} = 25^{\circ}\text{C}$		±0.2	±1	%
Over Temperature		V <sub>SENSE</sub> = 20mV to 100mV			±2	%
Total Output Error <sup>(1)</sup>				±0.75	±2.2	%
Over Temperature				±1	±3	%
Nonlinearity Error		V <sub>SENSE</sub> = 20mV to 100mV		±0.002	±0.1	%
Output Impedance	RO			1.5		Ω
Maximum Capacitive Load		No Sustained Oscillation		10		nF
VOLTAGE OUTPUT <sup>(2)</sup>		R <sub>L</sub> = 100kΩ to GND				
Swing to V+ Power Supply Rail				(V+) – 0.1	(V+) – 0.2	V
Swing to GND <sup>(3)</sup>				(V <sub>GND</sub> ) + 3	(V <sub>GND</sub> ) + 50	mV
FREQUENCY RESPONSE						
Bandwidth, INA193, INA196	BW	C <sub>LOAD</sub> = 5pF		500		kHz
INA194, INA197		$C_{LOAD} = 5pF$		300		kHz
INA195, INA198		$C_{LOAD} = 5pF$		200		kHz
Phase Margin		C <sub>LOAD</sub> < 10nF		40		degrees
Settling Time (1%)	tS	$V_{SENSE} = 10 \text{mV}$ to $100 \text{mV}_{PP}$ , $C_{LOAD} = 5 \text{pF}$		2		μs
NOISE, RTI						
Voltage Noise Density				40		nV/√Hz
POWER SUPPLY						
Operating Range	۷ <sub>S</sub>		+2.7		+13.5	v
Quiescent Current	IQ	$V_{OUT} = 2V$		700	900	μA
Over Temperature		V <sub>SENSE</sub> = 0mV		370	950	μΑ
TEMPERATURE RANGE						
Specified Temperature Range			-40		+125	°C
Operating Temperature Range			-55		+150	°C
Storage Temperature Range			-65		+150	°C
Thermal Resistance, SOT23	$\theta_{JA}$			200		°C/W

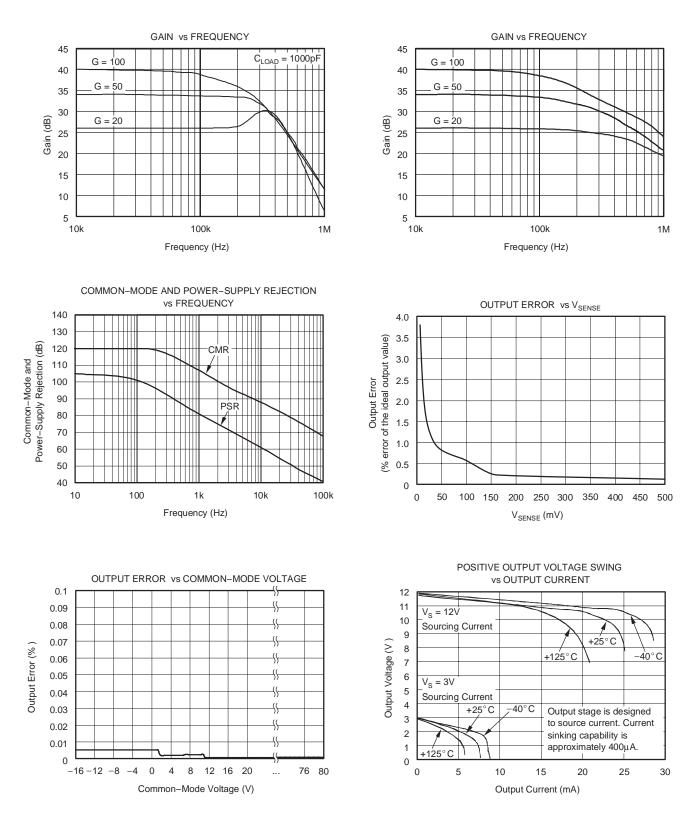
Total output error includes effects of gain error and V<sub>OS</sub>.
See Typical Characteristics curve *Output Swing vs Output Current*.
Specified by design.

SBOS307C - MAY 2004 - REVISED DECEMBER 2004



### **TYPICAL CHARACTERISTICS**

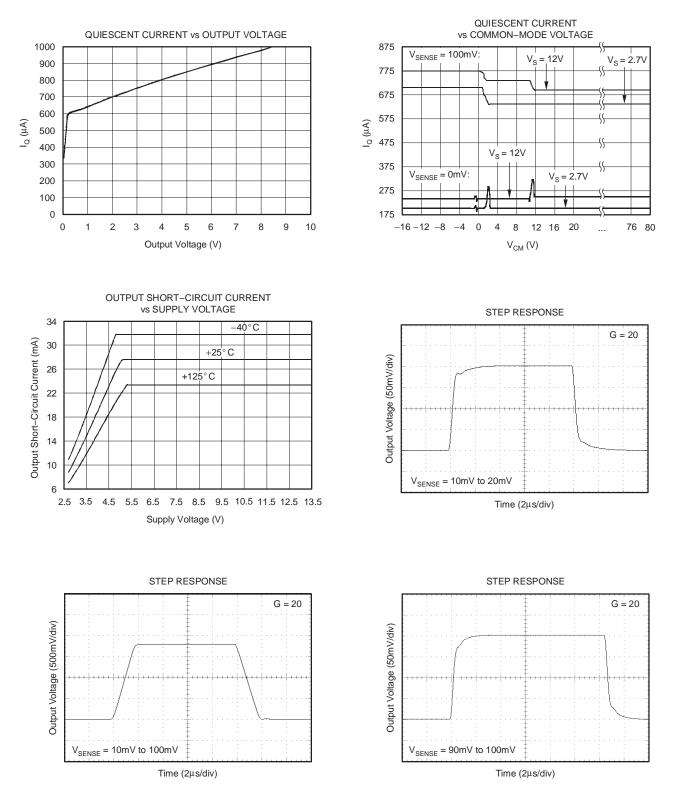
All specifications at  $T_A = +25^{\circ}C$ ,  $V_S = +12$ , and  $V_{IN+} = 12V$ , and  $V_{SENSE} = 100$  mV, unless otherwise noted.





# **TYPICAL CHARACTERISTICS (continued)**

All specifications at  $T_A = +25^{\circ}C$ ,  $V_S = +12$ , and  $V_{IN+} = 12V$ , and  $V_{SENSE} = 100$  mV, unless otherwise noted.

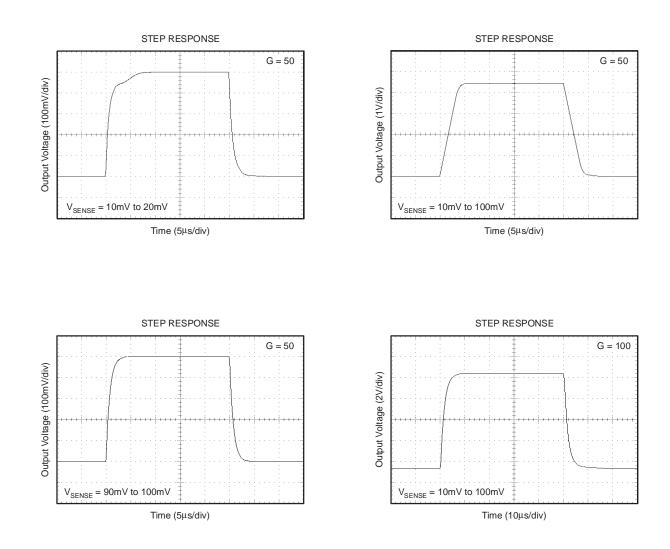


SBOS307C - MAY 2004 - REVISED DECEMBER 2004



## **TYPICAL CHARACTERISTICS (continued)**

All specifications at  $T_A = +25^{\circ}C$ ,  $V_S = +12$ , and  $V_{IN+} = 12V$ , and  $V_{SENSE} = 100$  mV, unless otherwise noted.



# APPLICATIONS INFORMATION BASIC CONNECTION

Figure 1 shows the basic connection of the INA19x. The input pins,  $V_{IN+}$  and  $V_{IN-}$ , should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

Power-supply bypass capacitors are required for stability. Applications with noisy or high impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

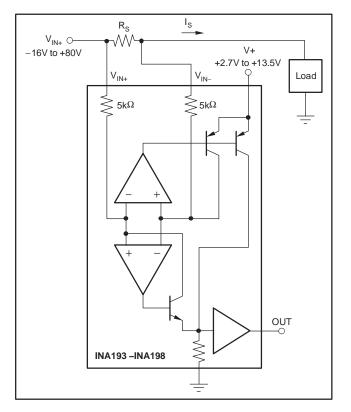


Figure 1. INA19x Basic Connection

# POWER SUPPLY

The input circuitry of the INA19x can accurately measure beyond its power-supply voltage, V+. For example, the V+ power supply can be 5V, whereas the load power-supply

voltage is up to +80V. The output voltage range of the OUT terminal, however, is limited by the voltages on the power-supply pin.

# SELECTING RS

The value chosen for the shunt resistor,  $R_S$ , depends on the application and is a compromise between small-signal accuracy and maximum permissible voltage loss in the measurement line. High values of  $R_S$  provide better accuracy at lower currents by minimizing the effects of offset, while low values of  $R_S$  minimize voltage loss in the supply line. For most applications, best performance is attained with an  $R_S$  value that provides a full-scale shunt voltage range of 50mV to 100mV. Maximum input voltage for accurate measurements is 500mV.

## TRANSIENT PROTECTION

The -16V to +80V common-mode range of the INA19x is ideal for withstanding automotive fault conditions ranging from 12V battery reversal up to +80V transients, since no additional protective components are needed up to those levels. In the event that the INA19x is exposed to transients on the inputs in excess of its ratings, then external transient absorption with semiconductor transient absorbers (zeners or Transzorbs) will be necessary. Use of MOVs or VDRs is not recommended except when they are used in addition to a semiconductor transient absorber. Select the transient absorber such that it will never allow the INA19x to be exposed to transients greater than +80V (that is, allow for transient absorber tolerance, as well as additional voltage due to transient absorber dynamic impedance). Despite the use of internal zener-type ESD protection, the INA19x does not lend itself to using external resistors in series with the inputs since the internal gain resistors can vary up to ±30%. (If gain accuracy is not important, then resistors can be added in series with the INA19x inputs with two equal resistors on each input.)

# **OUTPUT VOLTAGE RANGE**

The output of the INA19x is accurate within the output voltage swing range set by the power supply pin, V+. This is best illustrated when using the INA195 or INA198 (which are both versions using a gain of 100), where a 100mV full-scale input from the shunt resistor requires an output voltage swing of +10V, and a power-supply voltage sufficient to achieve +10V on the output.

SBOS307C - MAY 2004 - REVISED DECEMBER 2004



#### INPUT FILTERING

An obvious and straightforward location for filtering is at the output of the INA19x series; however, this location negates the advantage of the low output impedance of the internal buffer. The only other option for filtering is at the input pins of the INA19x, which is complicated by the internal 5k $\Omega$  + 30% input impedance; see Figure 2. Using the lowest possible resistor values minimizes both the initial shift in gain and effects of tolerance. The effect on initial gain is given by:

$$Gain Error\% = 100 - \left(100 \times \frac{5k\Omega}{5k\Omega + R_{FILT}}\right)$$
(1)

Total effect on gain error can be calculated by replacing the  $5k\Omega$  term with  $5k\Omega - 30\%$ , (or  $3.5k\Omega$ ) or  $5k\Omega + 30\%$  (or  $6.5k\Omega$ ). The tolerance extremes of  $R_{FILT}$  can also be inserted into the equation. If a pair of  $100\Omega \ 1\%$  resistors are used on the inputs, the initial gain error will be 1.96%. Worst-case tolerance conditions will always occur at the lower excursion of the internal  $5k\Omega$  resistor ( $3.5k\Omega$ ), and the higher excursion of  $R_{FILT} - 3\%$  in this case.

Note that the specified accuracy of the INA19x must then be combined in addition to these tolerances. While this discussion treated accuracy worst-case conditions by combining the extremes of the resistor values, it is appropriate to use geometric mean or root sum square calculations to total the effects of accuracy variations.

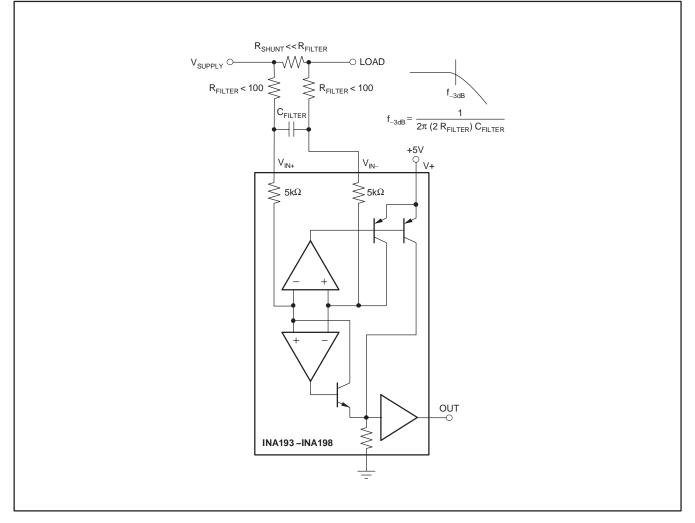


Figure 2. Input Filter (Gain Error – 1.5% to –2.2%)



INA193, INA194 INA195, INA196 INA197, INA198 SBOS307C – MAY 2004 – REVISED DECEMBER 2004

## **INSIDE THE INA19x**

The INA19x uses a new, unique internal circuit topology that provides common-mode range extending from –16V to +80V while operating from a single power supply. The common-mode rejection in a classic instrumentation amp approach is limited by the requirement for accurate resistor matching. By converting the induced input voltage to a current, the INA19x provides common-mode rejection that is no longer a function of closely matched resistor values, providing the enhanced performance necessary for such a wide common-mode range. A simplified diagram (see Figure 3) shows the basic circuit function. When the common-mode voltage is positive, amplifier A2 is active. The differential input voltage,  $(V_{IN+}) - (V_{IN-})$  applied across R<sub>S</sub>, is converted to a current through a 5k $\Omega$ resistor. This current is converted back to a voltage through R<sub>L</sub>, and then amplified by the output buffer amplifier. When the common-mode voltage is negative, amplifier A1 is active. The differential input voltage,  $(V_{IN+})$ –  $(V_{IN-})$  applied across R<sub>S</sub>, is converted to a current through a 5k $\Omega$  resistor. This current is sourced from a precision current mirror whose output is directed into R<sub>L</sub> converting the signal back into a voltage and amplified by the output buffer amplifier. Patent-pending circuit architecture ensures smooth device operation, even during the transition period where both amplifiers A1 and A2 are active.

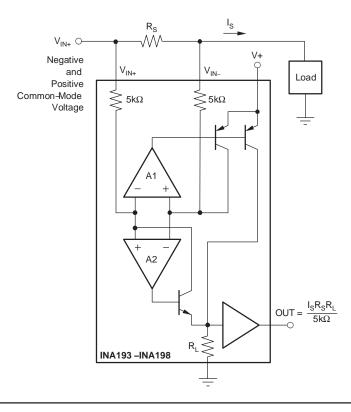


Figure 3. INA19x Simplified Circuit Diagram

INA193, INA194 INA195, INA196 INA197, INA198 SBOS307C - MAY 2004 - REVISED DECEMBER 2004



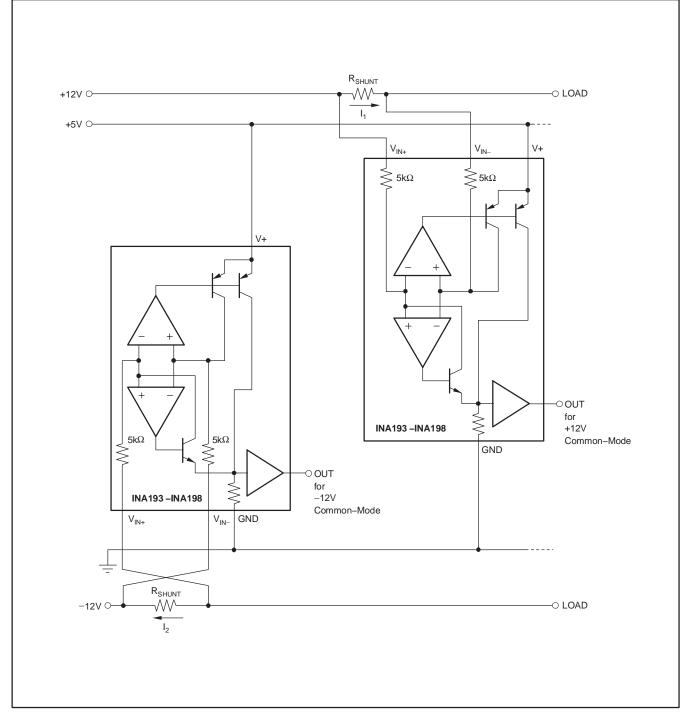
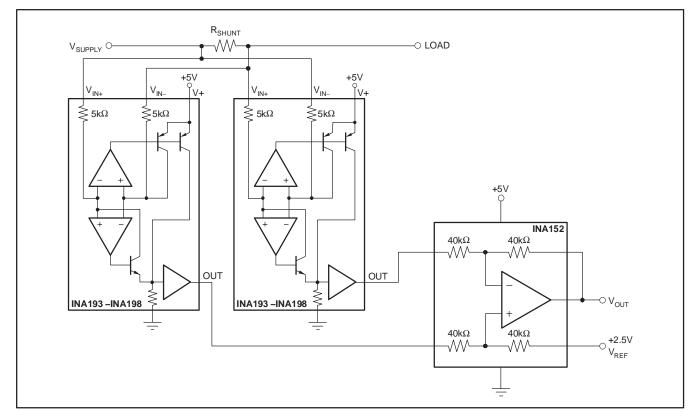


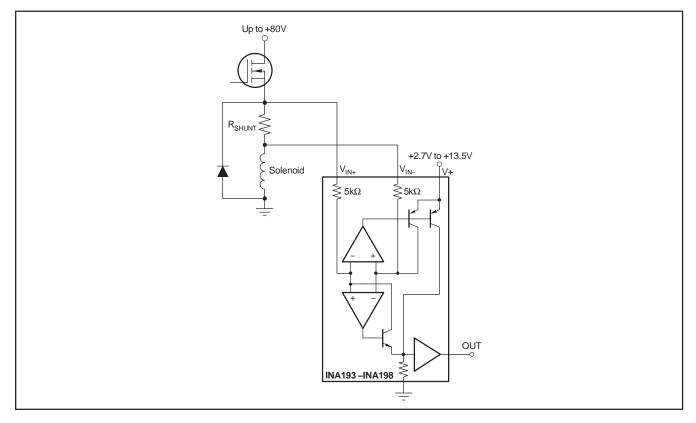
Figure 4. Monitor Bipolar Output Power-Supply Current



SBOS307C - MAY 2004 - REVISED DECEMBER 2004









SBOS307C - MAY 2004 - REVISED DECEMBER 2004



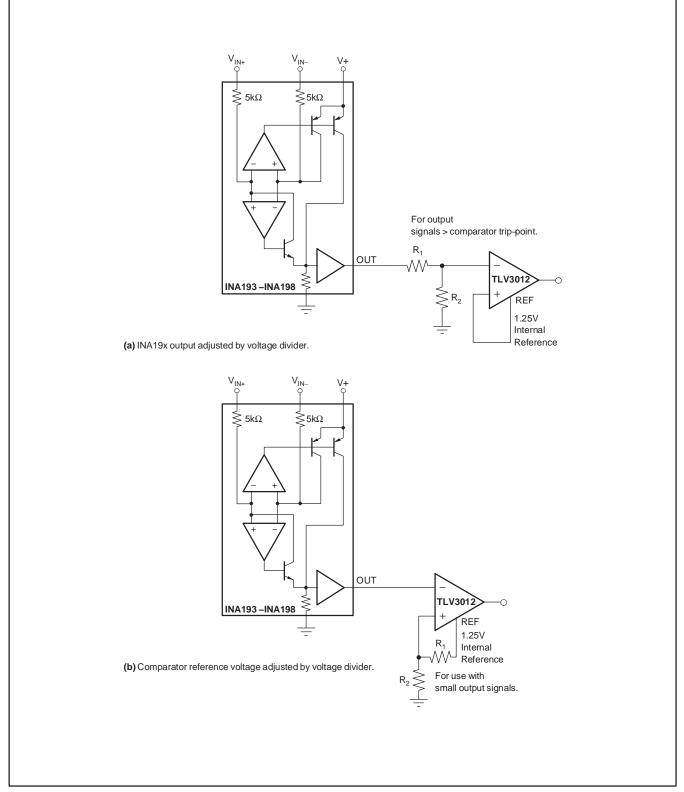


Figure 7. INA19x With Comparator

## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
INA193AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU NIPDAU	Level-3-260C-168 HR
INA193AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU NIPDAU	Level-3-260C-168 HR
INA194AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU	Level-3-260C-168 HR
INA194AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU	Level-3-260C-168 HR
INA195AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU	Level-3-260C-168 HR
INA195AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU	Level-3-260C-168 HR
INA196AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU NIPDAU	Level-3-260C-168 HR
INA196AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU NIPDAU	Level-3-260C-168 HR
INA197AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU NIPDAU	Level-3-260C-168 HR
INA197AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU NIPDAU	Level-3-260C-168 HR
INA198AIDBVR	ACTIVE	SOT-23	DBV	5	3000	None	CU NIPDAU	Level-3-260C-168 HR
INA198AIDBVT	ACTIVE	SOT-23	DBV	5	250	None	CU NIPDAU	Level-3-260C-168 HR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

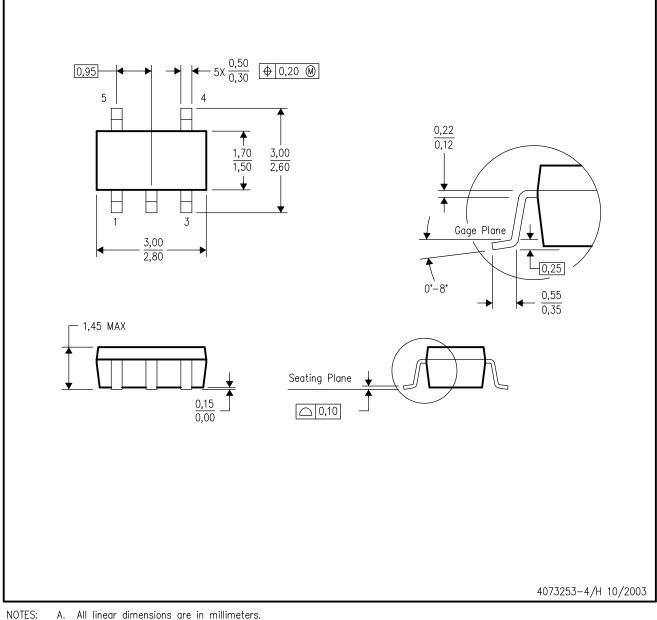
<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- Α. All linear dimensions are in millimeters.
  - Β. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold fla D. Falls within JEDEC MO-178 Variation AA. Body dimensions do not include mold flash or protrusion.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address:

Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2004, Texas Instruments Incorporated

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.